

**OK TO ENTER: /E.B./ IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

06/08/2011

Application No.: 10/553,573  
Applicants: Christian DUSSARRAT et al.  
Filed Internationally: April 8, 2004  
US National: October 17, 2005  
Title: METHODS FOR PRODUCING SILICON NITRIDE FILMS  
BY VAPOR-PHASE GROWTH  
TC/A.U.: 1715  
Examiner: Elizabeth A. Burkhart  
Docket No.: Serie 6070  
Customer No.: 40582

**AMENDMENT AFTER FINAL**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

In response to the Final Office Action mailed April 4, 2011, having a shortened statutory period for response set to expire on July 4, 2011, Applicants respectfully request reconsideration of the present application in view of the following amendments and/or remarks:

**Amendments to the Claims** begin on page 2 of this paper.

**Remarks** begin on page 4 of this paper.